

Fe₂VAl

limited"

• σ, and S are

moderate.

"Balanced but

PF of elongated bands in Full-Heusler materials

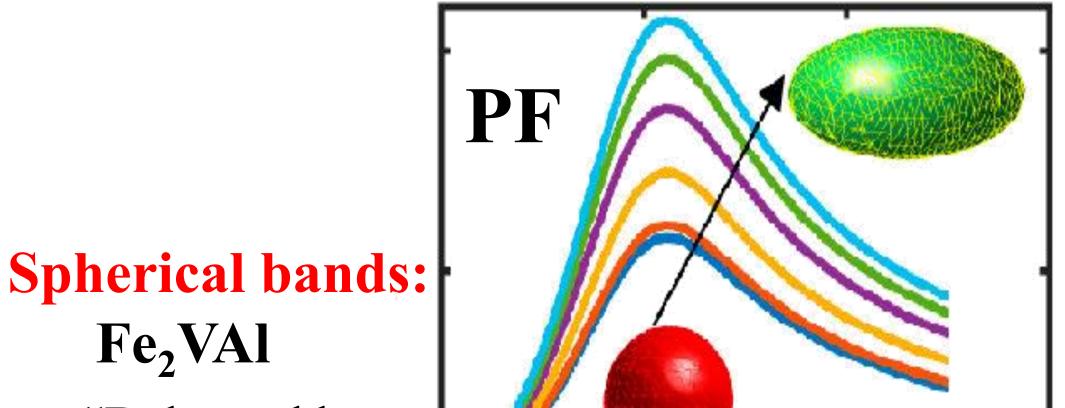
*Saff E Awal Akhtar, Bhawna Sahni and Neophytos Neophytou School of Engineering, University of Warwick, Coventry, UK



*saff-e-awal.akhtar@warwick.ac.uk



Elongated bands: Fe₂NbAl, Fe₂TiSn



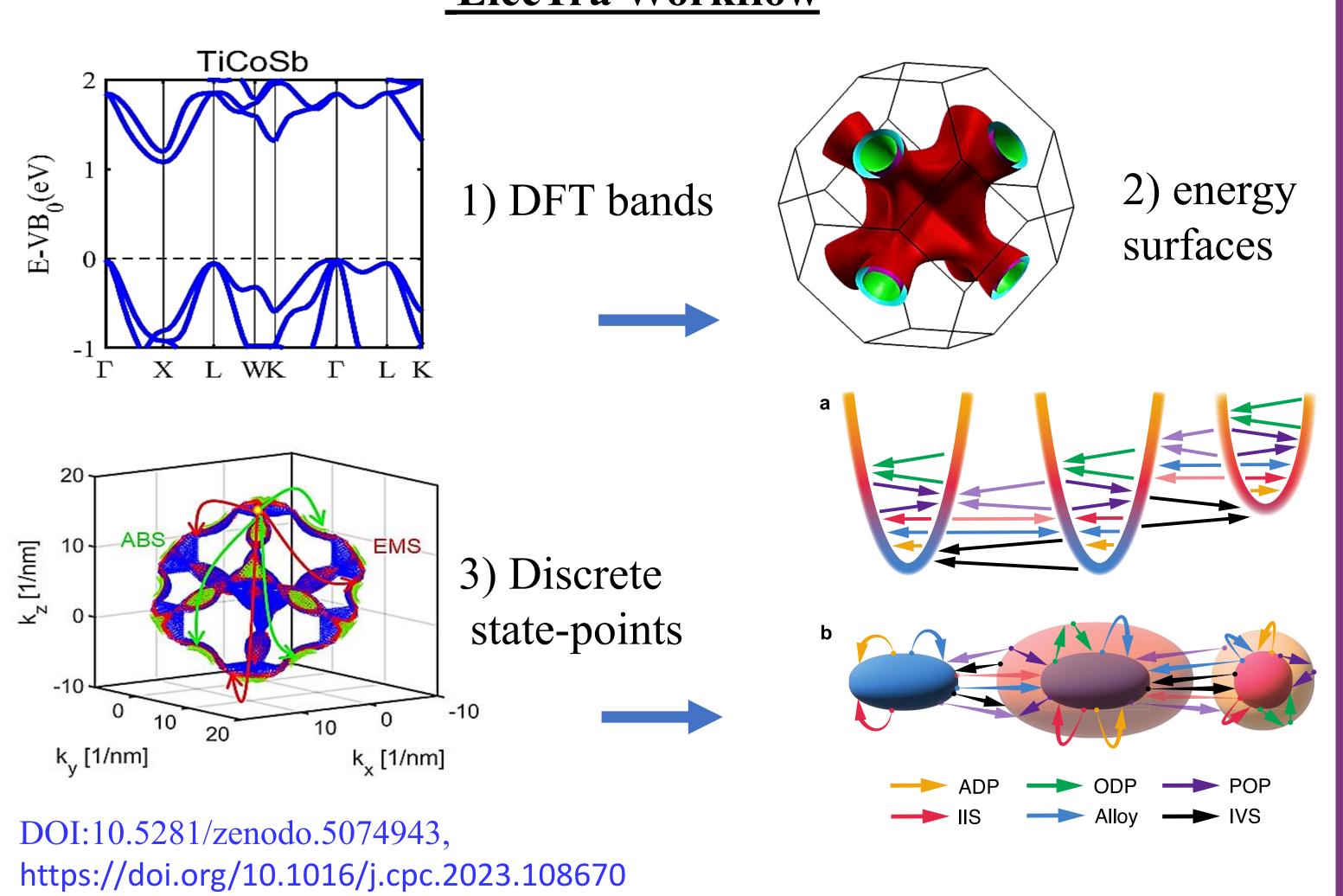
- "Best of both worlds"
- $\uparrow \sigma$ at one direction
- ↑S at other direction

$$m_{\rm C} = 3\left(\frac{1}{m_1} + \frac{2}{m_{\rm t}}\right)^{-1}$$
, $m_{\rm DOS} = (m_1 m_{\rm t}^2)^{1/3}$

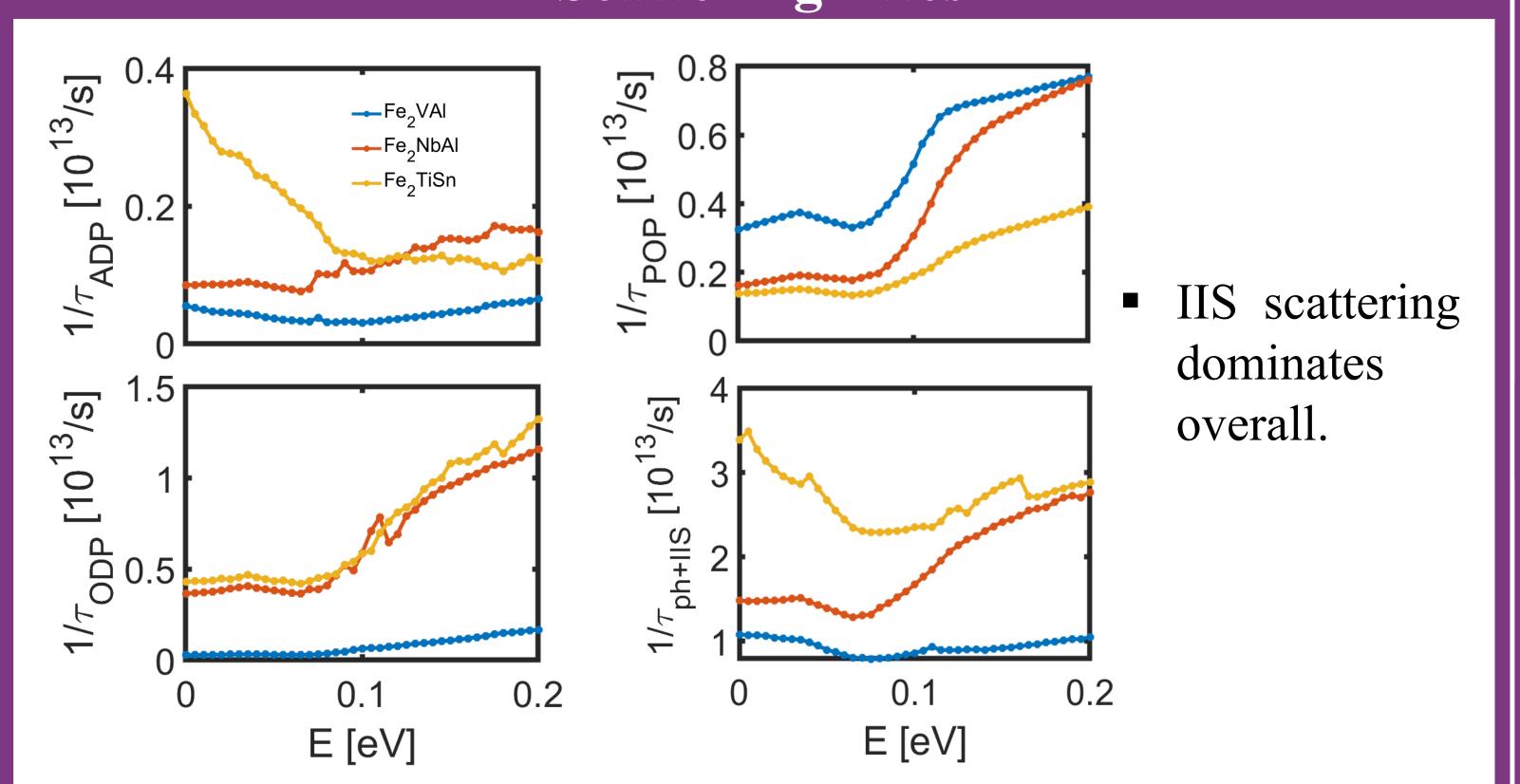
Methodology

- GGA-based DFT and DFPT calculations.
- ElecTra code for electronic transport based on Boltzmann Transport equations.

ElecTra Workflow



Scattering rates



Acknowledgement:

https://github.com/PatrizioGraziosi/ELECTRA

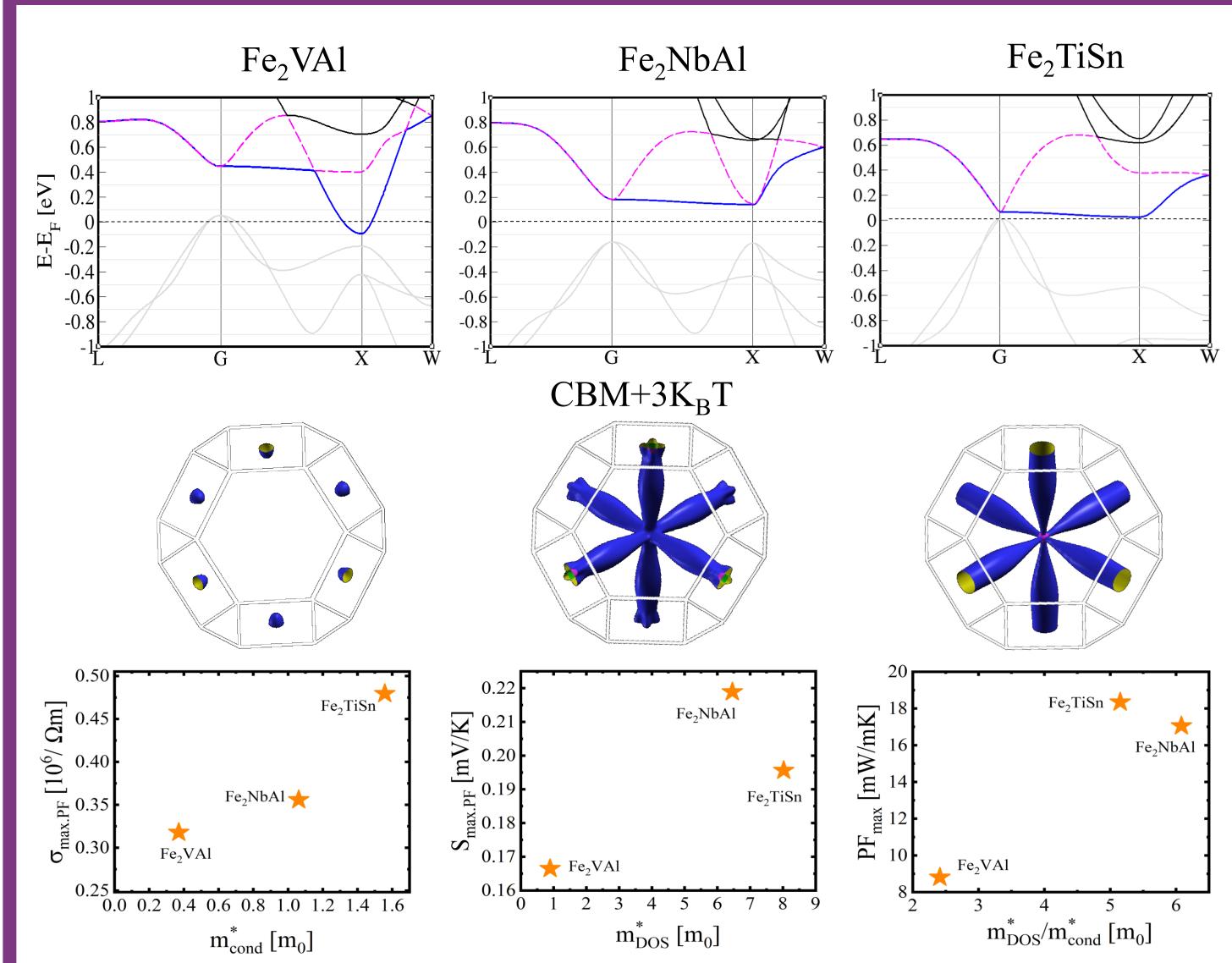
This work received funding from the European Union's Horizon 2020 research and innovative program (grant agreement No. 678763) and from the UK Research and Innovation fund (project reference EP/X02346X/1).





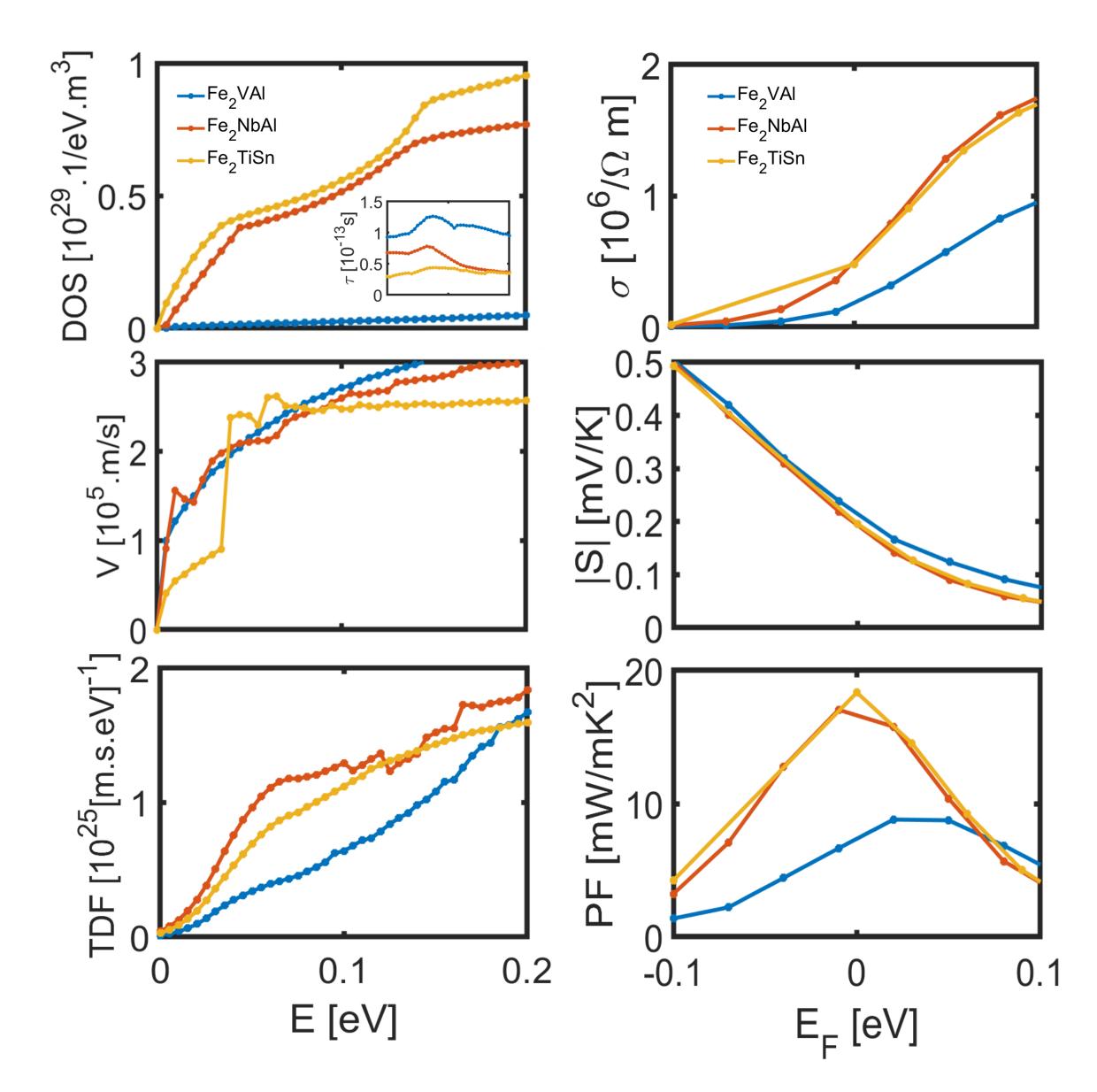


Electronic structures



Anisotropic pockets raise DOS but preserve velocities \rightarrow large m_{DOS}/m_{cond}

Transport Coefficients



The combination of large DOS and moderate effective conductivity mass (anisotropic pockets) results in the highest PF of Fe₂TiSn.

Conclusions

- Materials with elongated pockets have almost 2x increase in PF compared to spherical bands.
- In elongated bands anisotropy enhances both the DOS mass and the effective carrier density while keeping conductivity mass moderate, allowing larger σ and much higher PF.
- Spherical bands with low DOS and few valleys consistently lowest σ , S, and PF among the three.